

Low Phase Noise VCXO (for 120-200MHz Fund Xtal)

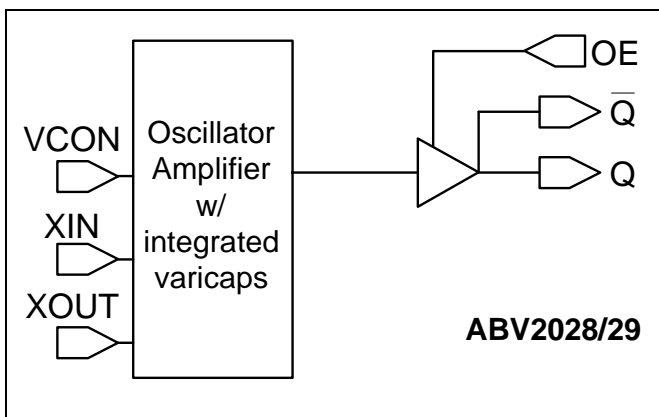
FEATURES

- 120MHz to 200MHz Fundamental Mode Crystal.
- Output range: 120 – 200MHz (no PLL).
- Low Injection Power for crystal 50uW.
- Sub 0.5pS RMS phase jitter (12kHz to 20MHz).
- PECL (ABV2028) or LVDS output (ABV2029).
- Integrated variable capacitors.
- Supports 2.5V or 3.3V-Power Supply.
- Available in 16-Pin (TSSOP or 3x3mm QFN).

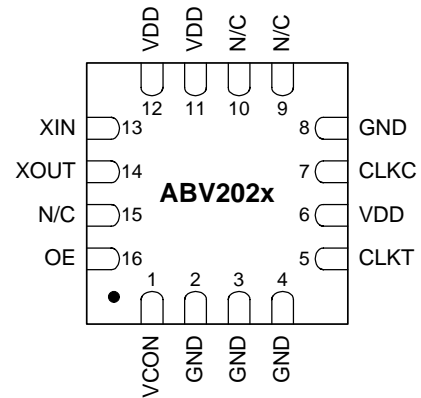
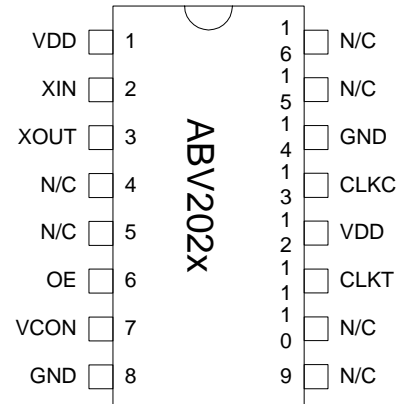
DESCRIPTION

The ABV2028/-29 are a family of VCXO IC's specifically designed to pull high frequency fundamental crystals. They achieve very low current into the crystal resulting in better overall stability. Their internal varicaps allow an on chip frequency pulling, controlled by the VCON input. Their very low jitter makes them ideal for the most demanding timing requirements.

BLOCK DIAGRAM



PIN CONFIGURATION (Top View)



OUTPUT ENABLE LOGICAL LEVELS

| Part # | OE | State |
|---------|-------------|----------------|
| ABV2028 | 0 (Default) | Output enabled |
| | 1 | Tri-state |
| ABV2029 | 0 | Tri-state |
| | 1 (Default) | Output enabled |

OE input: Logical states defined by PECL levels for ABV2028
 Logical states defined by CMOS levels for ABV2029

Low Phase Noise VCXO (for 120-200MHz Fund Xtal)

PIN DESCRIPTIONS

| Name | TSSOP Pin number | 3x3mm QFN Pin number | Type | Description |
|------|---------------------|-------------------------|------|--|
| XIN | 2 | 13 | I | Crystal input. See Crystal Specifications on page 2. |
| XOUT | 3 | 14 | I | Crystal output. See Crystal Specifications on page 2. |
| OE | 6 | 16 | I | Output enable pin. See Output Enable Logic Levels on page 1. |
| VCON | 7 | 1 | I | Voltage control input. |
| GND | 8, 14 | 2,3,4,8 | P | Ground. |
| CLKT | 11 | 5 | O | True output PECL (ABV2028) or LVDS (ABV2029) |
| CLKC | 13 | 7 | O | Complementary output PECL (ABV2028) or LVDS (ABV2029). |
| N/C | 4,5,9,10,15,16 | 9,10,15 | - | Not connected. |
| VDD | 1, 12 | 6,11,12 | P | +3.3V power supply. |

ELECTRICAL SPECIFICATIONS

1. Absolute Maximum Ratings

| PARAMETERS | SYMBOL | MIN. | MAX. | UNITS |
|-----------------------------------|----------|------|--------------|-------|
| Supply Voltage | V_{DD} | | 4.6 | V |
| Input Voltage, dc | V_i | -0.5 | $V_{DD}+0.5$ | V |
| Output Voltage, dc | V_o | -0.5 | $V_{DD}+0.5$ | V |
| Storage Temperature | T_s | -65 | 150 | °C |
| Ambient Operating Temperature* | T_A | -40 | 85 | °C |
| Junction Temperature | T_J | | 125 | °C |
| Lead Temperature (soldering, 10s) | | | 260 | °C |
| ESD Protection, Human Body Model | | | 2 | kV |

Exposure of the device under conditions beyond the limits specified by Maximum Ratings for extended periods may cause permanent damage to the device and affect product reliability. These conditions represent a stress rating only, and functional operations of the device at these or any other conditions above the operational limits noted in this specification is not implied.

* Note: Operating Temperature is guaranteed by design for all parts (COMMERCIAL and INDUSTRIAL), but tested for COMMERCIAL grade only.

2. Crystal Specifications

| PARAMETERS | SYMBOL | CONDITIONS | MIN. | MAX. | UNITS |
|-----------------------------|----------|--------------------------------|------|------|-------|
| Built-in Capacitance | CX+ | 120MHz to 200MHz (VDD=3.3V) | | 2 | pF |
| | CX- | | | 2 | |
| Inter-electrode capacitance | C_0 | | | | |
| C0/C1 ratio (gamma) | γ | | | 300 | - |
| Oscillation Frequency | OF | Fund. | 120 | 200 | MHz |

Low Phase Noise VCXO (for 120-200MHz Fund Xtal)

3. Voltage Control Crystal Oscillator (3.3V)

| PARAMETERS | SYMBOL | CONDITIONS | MIN. | TYP. | MAX. | UNITS |
|--------------------------------|---------------|--|-------------|---------|------|------------|
| VCXO Stabilization Time * | $T_{VCXOSTB}$ | From power valid | | | 10 | ms |
| VCXO Tuning Range | | $F_{XIN} = 100 - 200\text{MHz};$ $XTAL C_0/C_1 < 250$ $0V \leq VCON \leq 3.3V$ | | 200* | | ppm |
| CLK output pullability | | $VCON = 1.65V, \pm 1.65V$ | $\pm 100^*$ | | | ppm |
| On-chip Varicaps control range | | $VCON = 0 \text{ to } 3.3V$ | | 4 - 18* | | pF |
| Linearity | | | | | 10* | % |
| VCXO Tuning Characteristic | | | | 65 | | ppm/V |
| VCON input impedance | | | | 60 | | k Ω |
| VCON modulation BW | | $0V \leq VCON \leq 3.3V, -3\text{dB}$ | 25 | | | kHz |

Note: Parameters denoted with an asterisk (*) represent nominal characterization data and are not production tested to any specific limits.

4. General Electrical Specifications

| PARAMETERS | SYMBOL | CONDITIONS | MIN. | TYP. | MAX. | UNITS |
|---------------------------------|----------|--|----------|----------|----------|-------|
| Supply Current (Loaded Outputs) | I_{DD} | PECL/LVDS | | | 100/80 | mA |
| Operating Voltage | V_{DD} | | 2.97 | | 3.63 | V |
| Output Clock Duty Cycle | | @ 1.25V (LVDS) @ $V_{DD} - 1.3V$ (PECL) | 45 45 | 50 50 | 55 55 | % |
| Short Circuit Current | | | | ± 50 | | mA |

5. Jitter Specifications

| PARAMETERS | CONDITIONS | MIN. | TYP. | MAX. | UNITS |
|---------------------------------|---|------|------|------|-------|
| Period jitter RMS | At 155.52MHz, with capacitive decoupling between VDD and GND. | | 2.5 | | ps |
| Period jitter peak-to-peak | | | 18.5 | | |
| Accumulated jitter RMS | At 155.52MHz, with capacitive decoupling between VDD and GND. Over 10,000 cycles. | | 2.5 | | ps |
| Accumulated jitter peak-to-peak | | | 24 | | |
| Integrated jitter RMS at 155MHz | Integrated 12 kHz to 20 MHz | | 0.3 | | ps |

6. Phase Noise Specifications

| PARAMETERS | FREQUENCY | @10Hz | @100Hz | @1kHz | @10kHz | @100kHz | UNITS |
|---------------------------------|-----------|-------|--------|-------|--------|---------|--------|
| Phase Noise relative to carrier | 155.52MHz | -75 | -95 | -125 | -140 | -145 | dBc/Hz |

Note: Phase Noise measured at $VCON = 0V$

Low Phase Noise VCXO (for 120-200MHz Fund Xtal)

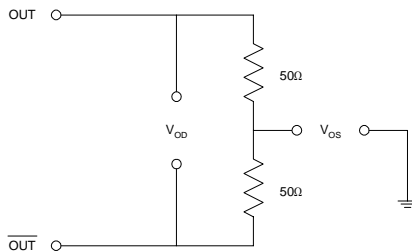
7. LVDS Electrical Characteristics

| PARAMETERS | SYMBOL | CONDITIONS | MIN. | TYP. | MAX. | UNITS |
|------------------------------|-----------------|--|-------|---------|----------|---------|
| Output Differential Voltage | V_{OD} | $R_L = 100\ \Omega$ (see figure) | 247 | 355 | 454 | mV |
| V_{DD} Magnitude Change | ΔV_{OD} | | -50 | | 50 | mV |
| Output High Voltage | V_{OH} | | | 1.4 | 1.6 | V |
| Output Low Voltage | V_{OL} | | 0.9 | 1.1 | | V |
| Offset Voltage | V_{OS} | | 1.125 | 1.2 | 1.375 | V |
| Offset Magnitude Change | ΔV_{OS} | | 0 | 3 | 25 | mV |
| Power-off Leakage | I_{OXD} | $V_{out} = V_{DD}$ or GND $V_{DD} = 0V$ | | ± 1 | ± 10 | μA |
| Output Short Circuit Current | I_{OSD} | | | -5.7 | -8 | mA |

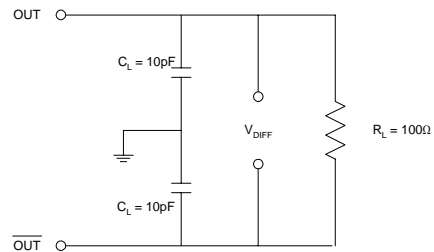
8. LVDS Switching Characteristics

| PARAMETERS | SYMBOL | CONDITIONS | MIN. | TYP. | MAX. | UNITS |
|------------------------------|--------|---|------|------|------|-------|
| Differential Clock Rise Time | t_r | $R_L = 100\ \Omega$ $C_L = 10\ pF$ (see figure) | 0.2 | 0.7 | 1.0 | ns |
| Differential Clock Fall Time | t_f | | 0.2 | 0.7 | 1.0 | ns |

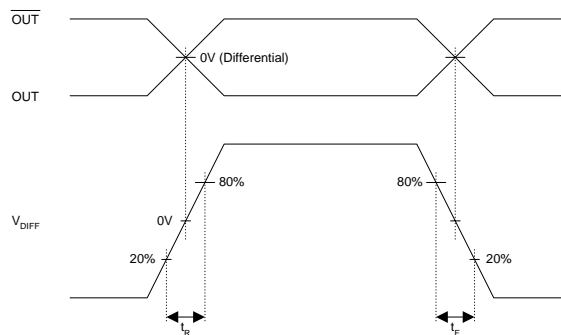
LVDS Levels Test Circuit



LVDS Switching Test Circuit



LVDS Transition Time Waveform



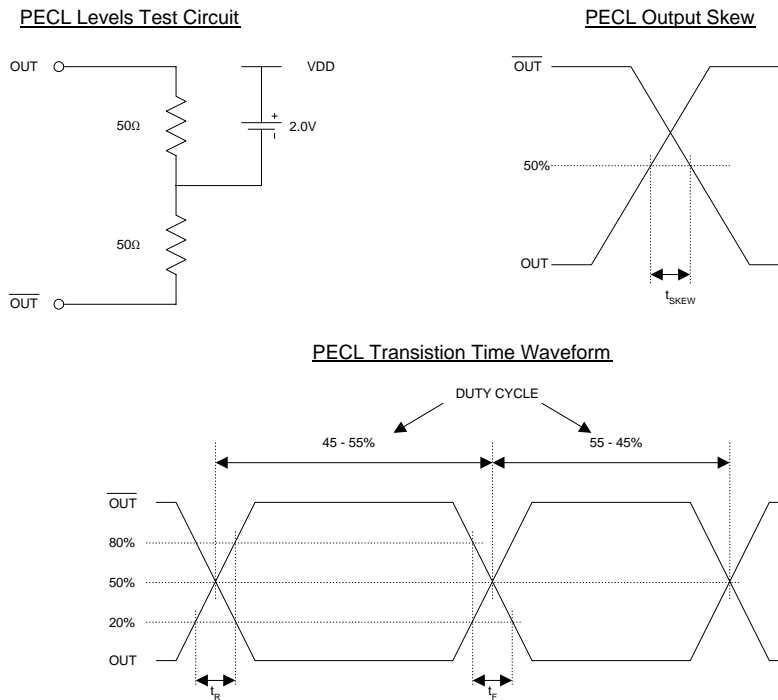
Low Phase Noise VCXO (for 120-200MHz Fund Xtal)

9. PECL Electrical Characteristics

| PARAMETERS | SYMBOL | CONDITIONS | MIN. | MAX. | UNITS |
|---------------------|----------|--|------------------|------------------|-------|
| Output High Voltage | V_{OH} | $R_L = 50 \Omega$ to $(V_{DD} - 2V)$ (see figure) | $V_{DD} - 1.025$ | | V |
| Output Low Voltage | V_{OL} | | | $V_{DD} - 1.620$ | V |

10. PECL Switching Characteristics

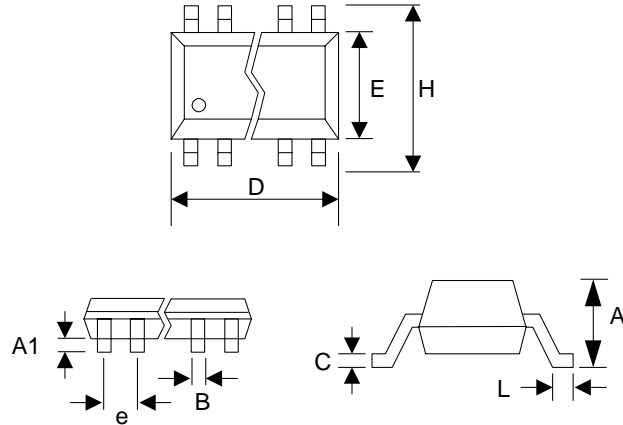
| PARAMETERS | SYMBOL | CONDITIONS | MIN. | TYP. | MAX. | UNITS |
|-----------------|--------|----------------|------|------|------|-------|
| Clock Rise Time | t_r | @20/80% - PECL | | 0.6 | 1.5 | ns |
| Clock Fall Time | t_f | @80/20% - PECL | | 0.5 | 1.5 | ns |



Low Phase Noise VCXO (for 120-200MHz Fund Xtal)

PACKAGE INFORMATION

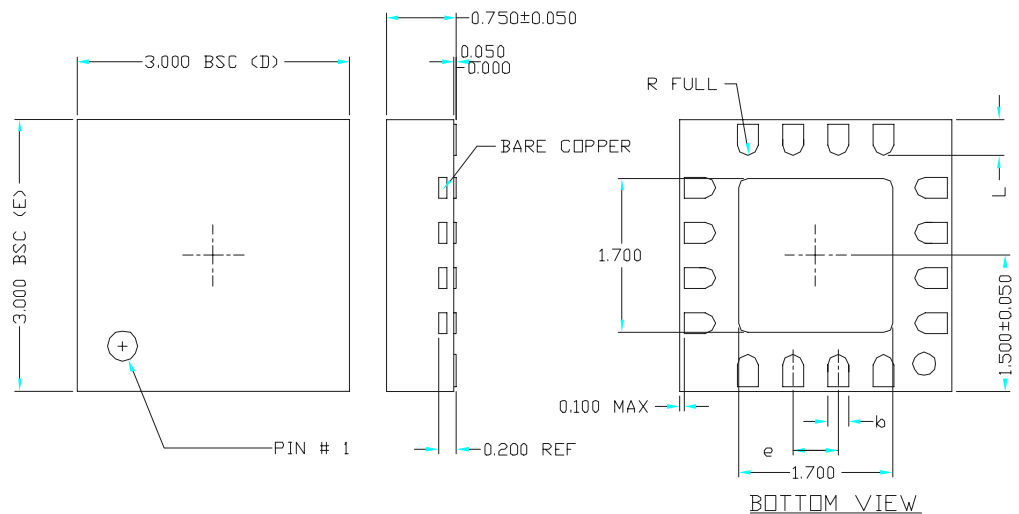
| 16 PIN TSSOP (mm) | | |
|---------------------|----------|------|
| Symbol | Min. | Max. |
| A | - | 1.20 |
| A1 | 0.05 | 0.15 |
| B | 0.19 | 0.30 |
| C | 0.09 | 0.20 |
| D | 4.90 | 5.10 |
| E | 4.30 | 4.50 |
| H | 6.40 BSC | |
| L | 0.45 | 0.75 |
| e | 0.65 BSC | |



3x3mm QFN

VARIATIONS:

| SYMBOL | 16 LD | | |
|--------|----------|------|------|
| | MIN | NDM | MAX |
| e | 0.50 BSC | | |
| k | 0.18 | 0.23 | 0.30 |
| L | 0.30 | 0.40 | 0.50 |
| ND | 4 | | |
| NE | 4 | | |



Low Phase Noise VCXO (for 120-200MHz Fund Xtal)

ORDERING INFORMATION

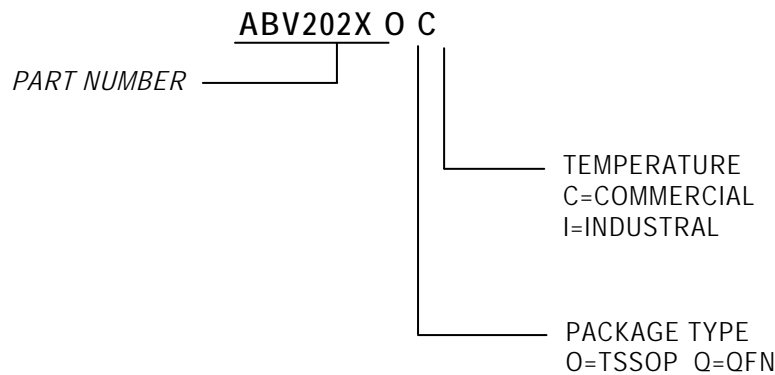
For part ordering, please contact our Sales Department:

30332 Esperanza., Rancho Santa Margarita, Ca 92688

Ph: 949-546-8000 Fax: 949-546-8001

PART NUMBER

The order number for this device is a combination of the following:
Device number, Package type and Operating temperature range



| <u>Order Number</u> | <u>Marking</u> | <u>Package Option</u> |
|---------------------|----------------|-----------------------|
| ABV2028OC | ABV2028OC | TSSOP - Tube |
| ABV2028OC-T | ABV2028OC | TSSOP - Tape & Reel |
| ABV2028QC | ABV2028QC | QFN - Tube |
| ABV2028QC-T | ABV2028QC | QFN - Tape & Reel |
| ABV2029OC | ABV2029OC | TSSOP - Tube |
| ABV2029OC-T | ABV2029OC | TSSOP - Tape & Reel |
| ABV2029QC | ABV2029QC | QFN - Tube |
| ABV2029QC-T | ABV2029QC | QFN - Tape & Reel |

Abracon Corporation, reserves the right to make changes in its products or specifications, or both at any time without notice. The information furnished by Abracon is believed to be accurate and reliable. However, Abracon makes no guarantee or warranty concerning the accuracy of said information and shall not be responsible for any loss or damage of whatever nature resulting from the use of, or reliance upon this product.

LIFE SUPPORT POLICY: Abracon's products are not authorized for use as critical components in life support devices or systems without the express written approval of the President of Abracon Corporation.